

PQMH11Z Datasheet



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DiGi Electronics Part Number PQMH11Z-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PQMH11Z

Description TRANS PREBIAS 2NPN DFN1010B-6

Detailed Description Pre-Biased Bipolar Transistor (BJT) 2 NPN - Pre-Bia

sed (Dual) 50V 100mA 230MHz 230mW Surface Mo

unt DFN1010B-6



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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|----------------------------------------------|----------------------------------------|
| PQMH11Z | Nexperia USA Inc. |
| Series: | Product Status: |
| | Active |
| Transistor Type: | Current - Collector (Ic) (Max): |
| 2 NPN - Pre-Biased (Dual) | 100mA |
| Voltage - Collector Emitter Breakdown (Max): | Resistor - Base (R1): |
| 50V | 10kOhms |
| Resistor - Emitter Base (R2): | DC Current Gain (hFE) (Min) @ Ic, Vce: |
| 10kOhms | 30 @ 5mA, 5V |
| Vce Saturation (Max) @ lb, lc: | Current - Collector Cutoff (Max): |
| 150mV @ 500μA, 10mA | 1μΑ |
| Frequency - Transition: | Power - Max: |
| 230MHz | 230mW |
| Grade: | Qualification: |
| Automotive | AEC-Q101 |
| Mounting Type: | Package / Case: |
| Surface Mount | 6-XFDFN Exposed Pad |
| Supplier Device Package: | Base Product Number: |
| DFN1010B-6 | PQMH11 |

Environmental & Export classification

8541.21.0075

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |



PQMH11

NPN/NPN resistor-equipped transistors; R1 = 10 $k\Omega$, R2 = 10 $k\Omega$

26 October 2015

Product data sheet

1. General description

NPN/NPN Resistor-Equipped Transistors (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PQMB11.

NPN/PNP complement: PQMD3.

2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit | |
|------------------|---------------------------|--------------------------|-----|-----|-----|-----|------|--|
| Per transistor | Per transistor | | | | | | | |
| V _{CEO} | collector-emitter voltage | open base | | - | - | 50 | V | |
| Io | output current | | | - | - | 100 | mA | |
| Per transistor | | | | | | | , | |
| R1 | bias resistor 1 | T _{amb} = 25 °C | [1] | 7 | 10 | 13 | kΩ | |
| R2/R1 | bias resistor ratio | | [1] | 8.0 | 1 | 1.2 | | |

[1] See section "Test information" for resistor calculation and test conditions.



NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|------------------------|---------------------------------------------------------------------------|--------------------------|
| 1 | GND1 | GND (emitter) TR1 | 5 7 7 | O1 I2 GND2 |
| 2 | I1 | input (base) TR1 | $\begin{bmatrix} 1 \\ 7 \end{bmatrix} \begin{bmatrix} 6 \\ \end{bmatrix}$ | |
| 3 | O2 | output (collector) TR2 | 2 5 | R1 R2 |
| 4 | GND2 | GND (emitter) TR2 | 8 5 | TR1 TR2 |
| 5 | 12 | input (base) TR2 | 3 4 | R2 R1 |
| 6 | 01 | output (collector) TR1 | Transparent top view | |
| 7 | 01 | output (collector) TR1 | DFN1010B-6 (SOT1216) | GND1 I1 O2 aaa-019894 |
| 8 | O2 | output (collector) TR2 | | ada 075557 |

6. Ordering information

Table 3. Ordering information

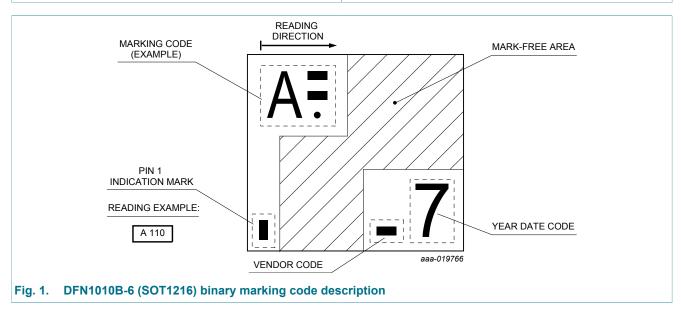
| Type number | Package | | |
|-------------|------------|----------------------------------------------------------------------------------------------|---------|
| | Name | Description | Version |
| PQMH11 | DFN1010B-6 | DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals | SOT1216 |

NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PQMH11 | A 001 |



NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

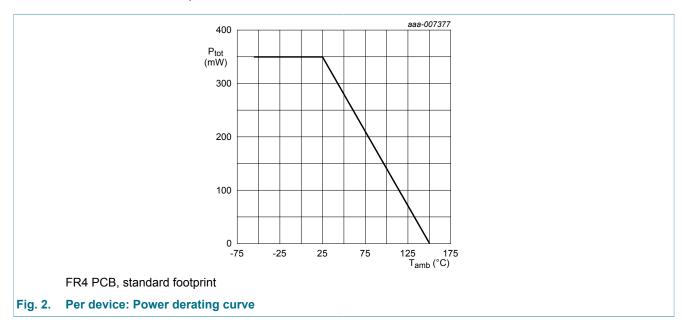
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------|--------------------------|-----|-----|-----|------|
| Per transis | tor | | , | | | |
| V _{CBO} | collector-base voltage | open emitter | | - | 50 | V |
| V_{CEO} | collector-emitter voltage | open base | | - | 50 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | 10 | V |
| VI | input voltage | positive | | - | 40 | V |
| | | negative | | - | -10 | V |
| Io | output current | | | - | 100 | mA |
| I _{CM} | peak collector current | | | - | 100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 230 | mW |
| Per device | | | 1 | ' | ' | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 350 | mW |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|---------------------------------------------------|-------------|-----|-----|-----|-----|------|
| Per transist | Per transistor | | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | - | 543 | K/W |
| Per device | | | | | | | |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | - | 357 | K/W |

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

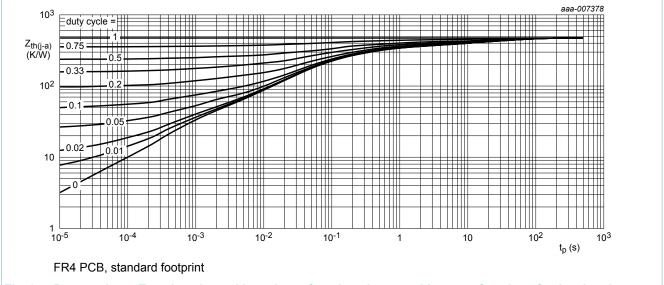


Fig. 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

10. Characteristics

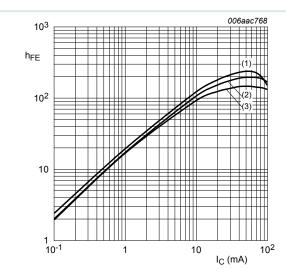
Table 7. **Characteristics**

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|--------------------|-----------------------------------------------|-------------------------------------------------------------------------------------------------|-----|-----|-----|-----|------|
| Per transist | or | | | | | | |
| I _{СВО} | collector-base cut-off current (emitter open) | V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C | | - | - | 100 | nA |
| I _{CEO} | collector-emitter cut-off | V _{CE} = 30 V; I _B = 0 A; T _{amb} = 25 °C | | - | - | 1 | μA |
| | current (base open) | V _{CE} = 30 V; I _B = 0 A; T _{amb} = 150 °C | | - | - | 5 | μA |
| I _{EBO} | emitter-base cut-off current (collector open) | $V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$ | | - | - | 400 | μA |
| h _{FE} | DC current gain | V _{CE} = 5 V; I _C = 5 mA; T _{amb} = 25 °C | | 30 | - | - | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$ | | - | - | 150 | mV |
| $V_{I(off)}$ | off-state input voltage | $V_{CE} = 5 \text{ V}; I_{C} = 100 \mu\text{A}; T_{amb} = 25 ^{\circ}\text{C}$ | | - | 1.1 | 0.8 | V |
| $V_{I(on)}$ | on-state input voltage | V_{CE} = 0.3 V; I_{C} = 10 mA; T_{amb} = 25 °C | | 2.5 | 1.8 | - | V |
| R1 | bias resistor 1 | T _{amb} = 25 °C | [1] | 7 | 10 | 13 | kΩ |
| R2/R1 | bias resistor ratio | | [1] | 0.8 | 1 | 1.2 | |
| C _C | collector capacitance | $V_{CB} = 10 \text{ V}; I_{E} = 0 \text{ A}; f = 1 \text{ MHz};$ $T_{amb} = 25 \text{ °C}$ | | - | - | 2.5 | pF |
| f _T | transition frequency | $V_{CE} = 5 \text{ V; } I_{C} = 10 \text{ mA; } f = 100 \text{ MHz;}$ $T_{amb} = 25 \text{ °C}$ | [2] | - | 230 | - | MHz |

^[1] See section "Test information" for resistor calculation and test conditions.

Characteristics of built-in transistor

NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω



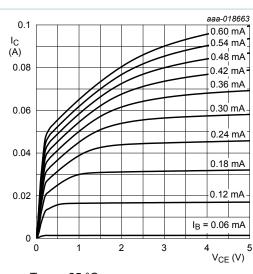
$$V_{CE} = 5 V$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb} = 25 \, ^{\circ}C$$

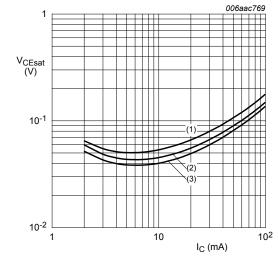
(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 4. DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$

Fig. 5. Collector current as a function of collectoremitter voltage; typical values



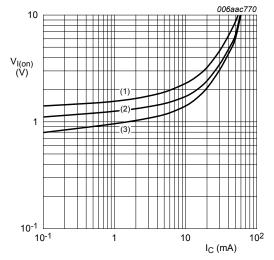
$$I_{\rm C}/I_{\rm B} = 20$$

(1)
$$T_{amb} = 100 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = -40 \, ^{\circ}C$$

Fig. 6. Collector-emitter saturation voltage as a function of collector current; typical values



$$V_{CE} = 0.3 \text{ V}$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

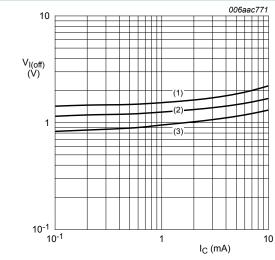
(2)
$$T_{amb}$$
 = 25 °C

(3)
$$T_{amb} = 100 \, ^{\circ}C$$

Fig. 7. On-state input voltage as a function of collector current; typical values

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NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω



$$V_{CE} = 5 V$$

(1)
$$T_{amb} = -40 \, ^{\circ}C$$

(2)
$$T_{amb}$$
 = 25 °C

(3) $T_{amb} = 100 \, ^{\circ}C$

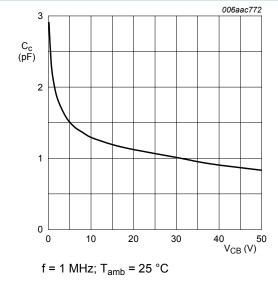
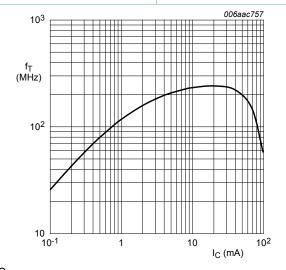


Fig. 9. Collector capacitance as a function of collectorbase voltage; typical values





V_{CE} = 5 V; T_{amb} = 25 °C

Fig. 10. Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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PQMH11Z Nexperia USA Inc. TRANS PREBIAS 2NPN DFN1010B-6

NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

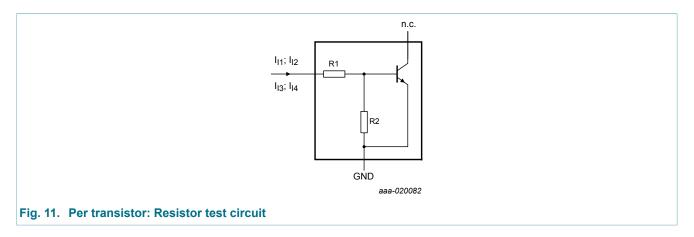
11.2 Resistor calculation

Calculation of bias resistor 1 (R1)

$$RI = \frac{V(I_{12}) - V(I_{11})}{I_{12} - I_{11}}$$

Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

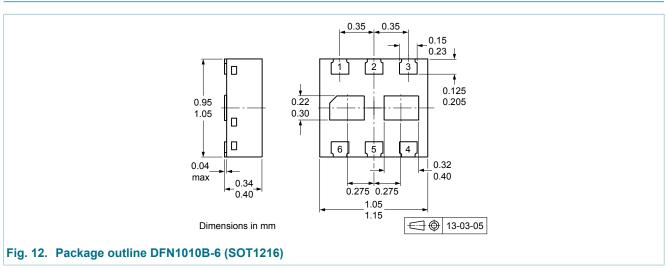


11.3 Resistor test conditions

Table 8. Resistor test conditions

| R1 (kΩ) | R2 (kΩ) | Test conditions | | | |
|---------|---------|-----------------|-----------------|-----------------|-----------------|
| | | I _{I1} | I _{I2} | I _{I3} | I _{I4} |
| 10 | 10 | 350 μΑ | 450 μΑ | -350 μΑ | -450 μΑ |

12. Package outline



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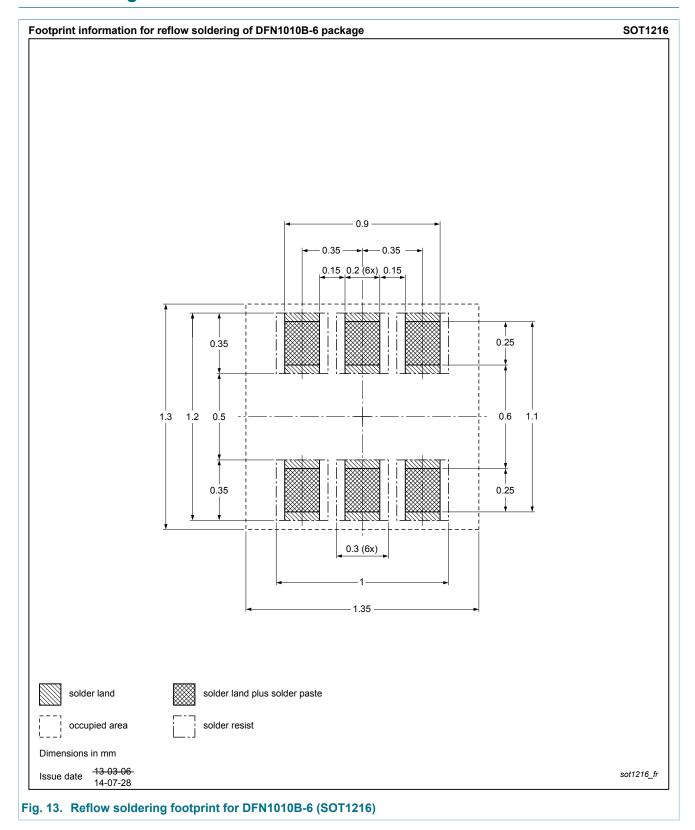
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NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

13. Soldering



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NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

14. Revision history

Table 9. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|---------------|--------------|--------------------|---------------|------------|
| PQMH11 v.1 | 20151026 | Product data sheet | - | - |

NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

15. Legal information

15.1 Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------------|--------------------|---------------------------------------------------------------------------------------|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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NPN/NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = 10 k Ω

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